

FORM PTO-1449		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. PKHF-05004US	SERIAL NO. 10/589,852 E 14985
LIST OF REFERENCES CITED BY APPLICANT <i>(Use several sheets if necessary)</i>				APPLICANT Noboru ICHINOSE	GROUP/ART UNIT 2829
				FILING DATE November 27, 2006	

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PATENT &amp; TRADEMARK OFFICE

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NO.	DATE	NAME	CLASS	SUB-CLASS	FILING DATE
	AA	6,897,560	05/24/2005	OTA			
	AB	7,319,249	01/15/2008	ICHINOSE			
	AC	6,977,397	12/20/2005	ICHINOSE			
	AD						
	AE						
	AF						

## FOREIGN PATENT DOCUMENTS

		DOCUMENT NO.	DATE	COUNTRY	CLASS	SUB-CLASS	TRANSLATION	YES	NO	PART.
	AG	2002-093243	03/29/2002	JAPAN (See U.S. 6,897,560)						ABS
	AH	2004-056098	02/19/2004	JAPAN (See U.S. 7,319,249 and U.S. 6,977,397)						ABS
	AI									
	AJ									

## OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

	AK	Harwig et al., "Electrical Properties of b-Ga <sub>2</sub> O <sub>3</sub> Single Crystals. II," Journal of Solid State Chemistry Vol. 23, pages 205-211, 15 January 1978. (Previously Submitted)
	AL	Ueda, N. et al., "Synthesis and Control of Conductivity of Ultraviolet Transmitting B-Ga <sub>2</sub> O <sub>3</sub> Single Crystals", in Applied Physics Letters, June 30, 1997, Vol. 70, Issue 26, pages 3561 to 3563. (Previously Submitted)
	AM	Tomm, Y. et al., "Floating Zone Growth of B-Ga <sub>2</sub> O <sub>3</sub> : A New Window Material for Optoelectronic Device Applications", In: Solar Energy Materials & Solar Cells, February, 2001, Vol. 66, Pages 369 to 374. (Previously Submitted)
	AN	Frank J. et al., "electrical Doping of Gas-Sensitive, Semiconducting Ga <sub>2</sub> O <sub>3</sub> Thin Films", In: Sensors and Actuators B: Chemical, August 1996, Vol. 34, pages 373 to 377. (Previously Submitted)
	AO	Harwig, T. et al., "Electrical Properties of B-Ga <sub>2</sub> O <sub>3</sub> Single Crystals. II", In: Journal of Solid State Chemistry, 15 January, 1978 (15.01.78), Vol. 23, pages 205 to 211. (Previously Submitted)
	AP	Japanese Office Action dated August 5, 2008 with Partial English Translation

EXAMINER	DATE CONSIDERED
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.